L	Hits	Search Text	DB	Time stamp
Number				11mb bamp
-	1	365/158,171.ccls. and cell\$1 and (magnetic adj layer) and (magnetic adj pole\$1) and (demagnetization adj field)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/30
-	3	365/\$.ccls. and cell\$1 and (magnetic adj layer) and (magnetic adj pole\$1) and (demagnetization adj field)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/30 15:06
-	6	365/\$.ccls. and cell\$1 and (magnetic near2 layer) and (magnetic near2 pole\$1) and (demagnetization near2 field)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/05/30 15:10
_	2	365/\$.ccls. and cell\$1 and (magnetic near2 layer) and (free near2 magnetic near2 pole\$1) and (demagnetization near2 field)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/30 15:11
-	2	cell\$1 and (magnetic near2 layer) and (free near2 magnetic near2 pole\$1) and (demagnetization near2 field) and (magnetic near2 flux)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/30 15:12
-	13	cell\$1 and (magnetic near2 layer) and (magnetic near2 pole\$1) and (demagnetization near2 field) and (magnetic near2 flux)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/30
-	363	cell\$1 with (magnetic near2 memory near2 device)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/30 15:19
-	138	365/171,158.ccls. and cell\$1 with (magnetic near2 memory near2 device)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/05/31 17:10
_	25	magnetic with layer and (free near2 pole\$1) and demagnetization and flux	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/30 15:21
_	2	365/171,158.ccls. and cell\$1 with (magnetic near2 memory near2 device) and pole\$1 and flux and demagnetization	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/30 15:28
_	1	365/\$.ccls. and (bit near2 cell\$1) and (magnetic near2 layer) and (free near2 magnetic near2 pole\$1) and (demagnetization near2 field)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/31 15:54
_	27	365/\$.ccls. and cell\$1 near2 (CS or "chip select") same level\$1 and signal\$1 and register	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/31 17:25
} —	31	cell\$1 near2 (CS or "chip select") same level\$1 and signal\$1 and register	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/31 17:57
_	1656	configur\$5 same (CS or "chip select") and register	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/31 17:58

Search History

6/17/04 12:54:26 PM

-	238	365/\$.ccls. and configur\$5 same (CS or	USPAT;	2004/05/31
		"chip select") and register	US-PGPUB;	17:58
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	201	365/\$.ccls. and configur\$5 same (CS or	USPAT;	2004/05/31
		"chip select") and level\$1 and signal\$1	US-PGPUB;	17:59
		and register	EPO; JPO;	
		-	DERWENT;	
			IBM TDB	
_	36	365/\$.ccls. and configur\$5 same (CS or	USPAT;	2004/05/31
		"chip select") with level\$1 and signal\$1	US-PGPUB;	18:07
		and register	EPO; JPO;	10.07
			DERWENT;	
			IBM TDB	
_	2	(memory near cell) and (flux with	USPAT;	2004/06/03
	_	absorb\$3 with layer)	US-PGPUB;	06:00
		assors with tayer,	EPO; JPO;	00.00
			DERWENT;	
			IBM TDB	
	14	(memory near cell) and (absorb\$3 with	USPAT;	2004/06/03
	1	layer) and flux	US-PGPUB;	06:02
		layer, and riak	EPO; JPO;	06.02
			DERWENT;	
			IBM TDB	
_	7	365/\$.ccls. and (magnetic near3 junction)	USPAT;	2004/06/03
_	1 '	and (permeabi\$4 with "100")	US-PGPUB;	06:11
		and (permeably) with 100)		06:11
			EPO; JPO; DERWENT;	
	40	365/\$.ccls. and (magnetic near3 memory	IBM_TDB	2004/06/02
	1 40	near3 array)and (coer\$7 with (smaller or	USPAT;	2004/06/03
		less))	US-PGPUB;	06:17
	i	1622//	EPO; JPO;	
			DERWENT;	
_	36	265/159 171 172 100 01 220 06 55 66 212	IBM_TDB	0004/06/00
-	36	365/158,171,173,189.01,230.06,55,66,213.cc		2004/06/03
		and (magnetic near3 memory near3 array)	US-PGPUB;	06:19
		and (flux with layer)	EPO; JPO;	
	1		DERWENT;	
_		265/150 171 172 100 01 220 06 55 66 612	IBM_TDB	0004/05/00
	52	365/158,171,173,189.01,230.06,55,66,213.cc		2004/06/03
		and (magnetic near3 junction) and (flux	US-PGPUB;	06:24
		with layer)	EPO; JPO;	
		,	DERWENT;	
			ממיתי אומד	1